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## **[502] Interfacial electron-phonon coupling at a $WS_2/hBN$ interface**

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The interfacial coupling between electronic states in a two-dimensional system and bosonic excitations in an adjacent substrate are still poorly characterized in van der Waals heterostructures. Here, we investigate the nature of such interactions in the electronic states of a  $WS_2/hBN$  stack via angle-resolved photoelectron spectroscopy. We resolve dispersing satellites separated from the intense quasiparticle  $WS_2$  valence band by energies comparable to  $\Gamma$  phonon modes in hBN. We derive a spectral function model to describe the interfacial coupling between charges in the  $WS_2$  layer and the lattice vibrations of the polar hBN substrate, which we employ to provide a qualitative estimation of the interaction strength.

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